Andreev LevelQubit

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We investigate the dynam ics of a two-level Andreev bound state system in a transm issive quantum point contact embedded in an rf-SQUID. Coherent coupling of the Andreev levels to the circulating supercurrent allows manipulation and read out of the level states. The two-level H am iltonian for the Andreev levels is derived, and the e ect of interaction with the quantum uctuations of the induced ux is studied. We also consider an inductive coupling of qubits, and discuss the relevant SQUID parameters for qubit operation and read out.

74.80 Fp, 85.25 Dq, 03.67 Lx

Recent observations of quantum coherence in superconducting circuits [1{5] have made superconducting qubits a realistic possibility. Superconducting qubits em ploy the phenom enon of macroscopic quantum coherence (MQC) [6], and operate with coherent superpositions of quantum states of a m acroscopic object - a superconducting condensate. An elementary MQC circuit consists of a hysteretic SQUD with a small capacitance Josephson tunnel junction (persistent current or ux qubit). The qubit is biased at half-integer external ux, and operates with the two degenerate current states corresponding to the clockw ise and counter-clockw ise circulating persistent currents. The coupling of the current states is due to quantum uctuations of the electric charge on the junction capacitor. Quantum measurements of the uctuating persistent current, or induced magnetic ux, provide means to read out the qubit state. Further modications of the ux qubits involve in plementation of multiple junction circuits [3,4]. In multiple junction MQC circuits, it is possible to employ one of the available dynam ic variables for qubit operation, and another one for qubit readout [4,8].

In this paper we consider a new type of superconducting qubit where the switching between the two persistent current states in a SQUID is achieved by employing a true m icroscopic system formed by the two-levelAndreev bound states in a superconducting atom ic-size quantum point contact embedded in the SQUID [9]. In this Andreev level qubit, the quantum information is stored in the m icroscopic quantum system, the Andreev bound states, sim ilar to non-superconducting solid state qubits like localized spins on impurities [10] or quantum dots [11]. Read-out of the Andreev level qubit is achieved by monitoring the m acroscopic persistent current or the induced ux in the SQUID, sim ilar to the MQC qubits.

The Josephson e ect in a single atom ic-size quantum point contact (QPC) embedded in a low -inductance nonhysteretic SQUID (Fig. 1) has rst been investigated by Koops et al. [12]; in this experiment, the averaged current-phase relation in the ground state was measured by performing a classical measurement of the induced ux. The results of this experiment, and also of other experiments on atom ic-size QPCs where the critical current [13] and current-voltage characteristics [14,15] have been investigated, are consistent with a theoretical picture in which the Andreev bound levels play the central role in the Josephson current transport [16].

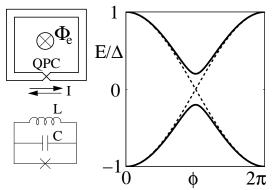


FIG.1. Left: Sketch of the Andreev level qubit – a non-hysteretic rfSQUID with a quantum point contact (QPC), and the equivalent circuit containing the Josephson junction and LC -oscillator. Right: The energy spectrum of the QPC with nite re ectivity (R = 0.04) (solid line), appears as a hybridization of the current states (R = 0) (dashed line).

The Andreev bound levels are form ed in a QPC due to Andreev re ections by the discontinuity of the superconducting phase at the contact in the presence of the applied current. The Andreev level wave functions are localized in the vicinity of the contact over a distance of the order of the superconducting coherence length, and the num ber of Andreev bound levels is limited to one pair of levels per conducting electronic m ode. Thus, a superconducting QPC m ay be viewed as a kind of quantum dot which contains a nite num ber of localized quantum states. In highly transm issive QPCs, the Andreev levels lie deep within the superconducting gap and are well decoupled from the continuum quasiparticle states in the electrodes.

The most important property for qubit applications is the coherent coupling of the Andreev levels to the supercurrent owing through the contact. This makes the Andreev levels accessible form an ipulations and form easurem ents. Extensive studies have shown that the tim e evolution of the Andreev levels can be controlled by applying resonant rf ux pulses [17] or by ram ping the external ux [9]. By these means, one can drive Andreev levels out of the ground state and prepare any excited state [18]. On the other hand, the time evolution of the Andreev levels changes the current through the QPC. Thus the QPC operates as a quantum switch which controls the direction of the circulating current in the SQUD. Perform ing quantum measurem ent of the circulating current, or of the corresponding induced ux, in the SQUID one is able to measure the state of the Andreev level system . Fidelity of such a measurem ent requires the qubit evolution to be slow on a time scale of intrinsic electromagnetic uctuations in the SQUD. Then the current (and induced ux) averaged over electrom agnetic uctuations will adiabatically follow the qubit evolution.

It is important to note that the interaction of the Andreev levels with electrom agnetic modes in the SQUID is an essential element of the qubit dynamics: To maintain the current switching, the plasm a frequency of the SQUID must be su ciently large. Furtheremore, since the current in the single-mode QPC undergoes strong quantum uctuations, the induced ux and hence the superconducting phase di erence, are also uctuating quantities, and the theory of the Andreev level qubit should include a full quantum mechanical treatment of the coupled Andreev levels and electrom agnetic uctuations.

To derive an elective quantum H am iltonian describing coupled Andreev levels and electrom agnetic uctuations, we employ a path integral approach commonly used in MQC theory [19]. The central problem here is to extend the theory, originally developed for tunnel junctions, to the for us interesting case of high transmission QPCs; this problem is solved by using the exact boundary condition in the action instead of the tunnel H am iltonian. Following Ref. [19], we present the evolution operator for the system on the form,

$$U = D e^{iS_{osc}[]=h} D^{2} {}_{L}D^{2} {}_{R} e^{iS_{J}=h};$$
(1)

where the integration is performed over the superconducting phase di erence (t) and N am bu-G rassm an elds $_{L,R}$ (r;t) representing electronic degrees of freedom in the left and right electrodes respectively. The action $S_{osc}[$] describes an LC -oscillator formed by the junction capacitance C and the superconducting loop inductance L (see Fig. 1), while the action S_J describes the Josephson junction.

To derive the action for the Josephson junction, we consider the two superconducting reservoirs coupled via a single-channel localized scatterer. The scatterer is represented by a norm allelectron scattering matrix, which im - poses the boundary condition for the quasiclassical wave functions of the quasiparticles in the reservoirs. The microscopic Ham iltonian for the reservoirs,

$$H = \begin{cases} X & Z \\ dr & y\hat{h} ; \hat{h} = \frac{p^2}{2m} \\ z + x; (2) \end{cases}$$

is considered within the mean eld approximation, the superconducting phase being gauged out and included in the boundary condition. The_RHamiltonian generates the Lagrangian, $L = \sum_{I,R} dr$ (ihe_t \hat{h}). In the boundary condition, which connects the elds L_{R} (0;t) at the contact, the energy dependence of the scattering matrix on the scale of can be neglected, so that the same matrix describes both the electrons and holes. Furtherm ore, without loss of generality, it is possible to eliminate constant scattering phases from the boundary condition and include them in the positive and negative momentum components of the elds

(r;t). W ithin the quasiclassical approximation, such a transformation will not a ect the Hamiltonian in Eq. (2). The boundary condition can then be written on the form, (t) = $\frac{de}{p} \frac{i}{z} \frac{(t)^{-2}}{pL} p_{L}(0;t)$ (1 + r) _R (0;t) = 0; where d = $\frac{D}{D}$ and r = $\frac{P}{R}$ are real transmission and re ection amplitudes respectively. This boundary condition is incorporated into the junction action S_J by means of the Lagrange eld (t),

$$e^{iS_{J}=h} = D^{2} e^{(i=h)^{R} dt(L)}$$
 (3)

We will see later that the ferm ionic eld (t) describes the Andreev levels.

Integration over the rapidly varying ferm ionic elds in the electrodes, (r;t), yields the electrodes

$$e^{iS_{eff}[]=h} = D^{2} e^{(i=h) dt_{1} dt_{2} (t_{1})G(t_{1};t_{2}) (t_{2})}; (4)$$

where

$$G(t_{1};t_{2}) = \frac{D}{(1+r)^{2}}e^{i_{z}}(t_{1})^{=2}g(t_{1} + t_{2})e^{i_{z}}(t_{2})^{=2}$$
$$g(t_{1} + t_{2}); \quad g(!) = \frac{X}{(h! + h)^{-1}}; \quad (5)$$

Equation (5) provides the required generalization of the the e ective action of the tunnel theory [19] to junctions with arbitrary transparency. In the low frequency limit, ! = h, the G reen's function g(!) reduces to a simple form, g(!) = $(F_F =)(h! + F_X)(F_F)$ is the density of states at the Ferm i level), which leads to the local-in-time e ective Lagrangian, G $(t_1;t_2) = G(t_1)$ $(t_2 = t_2)$,

G (t) =
$$ih \theta_t \frac{1}{4} h \theta_t z + 0 z e^{i = 2}$$
;
(6)

with $z = [\cos(-2) + ir \sin(-2)]$:

Equation (6) describes a two-level ferm ionic system. Under stationary conditions, $Q_t = 0$, the spectrum of the system, h! = E_a , E_a $\cos^2(=2) + R \sin^2(=2)$; coincides with the Andreev level spectrum [16], shown in Fig. 1. It follows from this equation that the assum ed low -frequency approxim ation is appropriate for transparent contacts, R 1**,**at where the Andreev level energy is small, E a .Toderive the Ham iltonian for the Andreev two-level system, it is convenient st to eliminate the time derivative of the phase in Eq. (6) by m eans of a unitary rotation, and then to use the relation, G (t) = $ih Q_t$ H_a , to obtain

$$\hat{H}_{a} = \begin{array}{c} 0 & ze^{ir = 2} \\ ze^{ir = 2} & 0 \end{array}$$
; (7)

This equation is the rstmain result of the present paper [20].

The slow dynamics in transparent contacts, R 1, is described by two variables, (t) and (t). This is rather di erent from tunnel contacts with D 1, where the e ective action only depends on the phase di erence and basically reduces to the potential Josephson energy [19]. This di erence is easily understood if one takes into account that the Andreev levels in tunnel junctions are close to the gap edge, E_a , making (t) a rapid variable. Integration over in Eq. (4) assuming small D in Eq. (5), recovers the e ective action of Ref. [19].

Let us now consider the current through the junction. The statistically averaged current hIi can be expressed through the Josephson part, U_J , of the evolution operator in Eq. (1), hIi = 2ei(=) ln hJji: In terms of the e ective action, the equation for the averaged current reduces to the form hIi = Tr($\hat{1}$), where is the density m atrix, and $\hat{1}$ is the current operator of the two-level A ndreev system,

$$\hat{I} = \frac{2e}{h} \frac{d\hat{H_a}}{d} = \frac{eI()}{h} \frac{0}{e^{ir}} \frac{e^{-ir}}{2} \frac{e^{-ir}}{2}$$

I() = D sin(=2). The current operator \hat{f} does not commute with the Hamiltonian $\hat{H_a}$, which is a consequence of the normal electron rejection at the QPC. Therefore the Andreev levels consist of superpositions of the current eigenstates, unless R = 0, and hence the current expectation value in the Andreev state, $I_a =$ (2e=h)(dE_a=d) = (e=2h)(D²=E_a)sin, does not coincide with the current eigenvalues, eI=h, which are evaluated during the quantum measurements. Furthermore, the Andreev level current undergoes quantum uctuations with the spectral function (cf. Ref. [21]), $S(!) = I_a^2 R \tan^2(=2)$ (! $2E_a$): In the SQUID geometry, these uctuations generate strong quantum uctuations of the phase.

We now take the quantum dynamics of the superconducting phase into the consideration. The quantum Hamiltonian of the LC-oscillator associated with the action S_{osc} [] in Eq. (1) has the form, $\hat{H}_{osc} =$ $q \frac{(h@)^2=2M}{8E_LE_C=h^2}$, $E_C = e^2=22$; where $M = h^2=8E_C$, ! = $8E_LE_C=h^2$, $E_C = e^2=2C$, $E_L = (hc=2e)^2$ (1=L), and ~ is related to the induced ux, ~= (ch=2e) ~.

In the practically important case of small loop inductance, $E_J = E_L$, the SQUID is in the non-hysteretic regime, and the induced ux is small, ~ 1. Introducing the phase di erence _e related to a stationary external ux we expand the Ham iltonian in Eq. (7) over small ~; then the Ham iltonian of the whole system in the current eigenbasis takes the form,

$$\hat{H} = \cos \frac{e}{2} _{z} + r \sin \frac{e}{2} _{x} + \frac{I(e)}{2} \sim _{z} + \hat{H}_{osc}$$
(9)

This Hamiltonian describes a spin degree of freedom linearly coupled to an oscillator, the steady state of the oscillator being shifted from the origin by I=2M !² depending on the spin direction (direction of the current in the junction). We are interested in the case when the induced ux adiabatically follows the evolution of the Andreev levels. This regime corresponds to a large oscillator frequency com pared to the Andreev level spacing, 2E_a. In this case, the oscillator can be assumed to h! = \sim I=2M $!^2$, since be in the ground state, \prime_0 (), the probability of transitions among the oscillator levels is small. A veraging out the ground state phase uctuations [22], we nally arrive at the e ective Ham iltonian describing the Andreev level qubit,

$$\hat{H}_{q} = \cos \frac{e}{2} _{z} + q_{0} r \sin \frac{e}{2} _{x}$$
 (10)

The factor, $q_D = \exp I^2=4M h!^3$, is the overlap integral between the oscillator ground state wave functions for di erent current directions, '_0(). The averaged value of the induced phase is then given by h^i = (I=2M !^2)Tr(_z), which yields the relation between the induced ux operator and the current operator, $\hat{c} = (L=c) \hat{I}$. Therefore quantum m easurem ent of the ux on a time scale $1=! < < h=2E_a$ will allow correct evaluation of the Andreev level state.

The qubit Ham iltonian (10) is another main result of this paper. Equation (10) is equivalent to the Ham iltonian of non-interacting Andreev levels, Eq. (9), but with reduced re ectivity, $\mathcal{R} = q_0^2 R \cdot O$ nem ay interpret this reduction as the e ect of the inertia of the loop oscillator, which makes it more di cult for the Andreev levels to

switch direction of the current. The e ect becomes increasingly strong in the limit of a classical oscillator with large "m ass". This renom alization e ect leads to reduction of the Andreev level energy E_a ! E_a , and hence to the reduction of the frequency of the qubit rotation, remaning the results of Ref. [17,18] essentially the same. This might be important for practical applications, because it would allow the frequency of the qubit rotation to be tuned by choosing circuit parameters rather than by tuning the contact re ectivity.

The following chain of inequalities summarizes the requirements for the Andreev level qubits,

$$\begin{array}{ccc} p - \\ 2 & \vec{R} & h! & E_J & E_L : \end{array}$$
(11)

These requirem ents are consistent with the typical circuit parameters of the experimental MQC qubits [3,4]. The critical current in the QPC is close to the maximum supercurrent of a single mode, I e =h (400nA for N b), and the Josephson energy, $E_{\rm J}$. A ssuming L 0.1nH, and C 0.1pF, we estimate ! 10 sec 1, 10¹³sec ¹ $10_{\rm Nb}$ =h. For these values, the and E $_{\rm L}$ =h q0-factor is of order unity, and the relectivity of the contact must be small, R 0:01, which is, in principle, accessible in the experim ents with atom ic-size QPC [13,15]. However, even a slight increase of the inductance will signi cantly decrease the q_0 -factor, and the constraint on the bare contact re ectivity will become less restrictive. In sum m ary, we estim ate the upper bound for the qubit operation frequency to be about 10^{10} sec¹.

The qubit operation frequency must signi cantly exceed the relaxation and dephasing rates of the qubit. The relaxation and dephasing mechanisms (external ux uctuations, radiation, etc.), which have been extensively discussed for the MQC ux qubits [7], are also relevant for the Andreev level qubit. The interaction of the Andreev levels with microscopic degrees of freedom in the contact, prim arily with the phonons, does not im pose any further limitations. Investigation of this problem has shown [23] that the relaxation rate is very sensitive to the Andreev \tilde{R}^{2} $_{ph}^{1}$ () at 1 level spacing: for small spacing, E_a . For R < 0.01 this relaxsm all tem perature, T ation rate is smaller than the qubit operation frequency by at least a factor of 10^4 .

We conclude with a discussion of the qubit-qubit interaction. Let us consider an inductive coupling as the most relevant interaction for the ux qubits. This coupling will introduce hybridization of the loop oscillators, which is described by inserting the inductance matrix in the H_{osc} term in Eq. (9). The averaging over ux uctuations is conveniently perform ed using the oscillators norm alm odes. The averaging procedure leads to the qubit H am iltonians in Eq. (10) with slightly di erent dressing factors, and to a H am iltonian of direct qubit-qubit interaction. For the two qubits the elective interaction has the form, H_{int} = (e=ch² (M I₁I₂) z1 z2, where M is the mutual inductance. The two-qubit con guration m ay consist, in particular, of a single QPC with two conducting modes; in this case M = L.

In conclusion, we have developed a theory for the Andreev level qubit, a device consisting of a SQUID with a quantum point contact, combining the features of microscopic and macroscopic quantum systems. We derived the two-level H am iltonian for the Andreev levels and showed that it is strongly dressed by the quantum uctuations of the induced ux. We also derived the effective interaction H am iltonian for inductively coupled qubits, and discussed the relevant circuit param eters for the qubit operation and read out.

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- [1] Y.Nakammura et al, Nature 398, 786 (1999).
- [2] J.R. Friedm an et al., Nature 406, 43 (2000).
- [3] C H. van der W alet al, Science 290, 773 (2000).
- [4] D.Vion et al., Science 296, 886 (2002).
- [5] Yang Yu, et al., Science 296, 889 (2002).
- [6] A.J.Leggett, in Proceedings of the NATO ASI, Les Arcs, 1983 ed. A M. Goldman and SA.W olf (Plenum, New York, 1984).
- [7] Y.Makhlin, et al., Rev.M od. Phys. 73, 357 (2001).
- [8] A.B.Zorin, Physica C 398, 284 (2002).
- [9] J. Lantz, et al., Physica C, 368, 315 (2002).
- [10] B E.Kane, Nature 393, 133 (1998).
- [11] D. Loss and D P. D iV inchenzo, Phys. Rev. A 57, 120 (1998).
- [12] M.C.Koops, et al, Phys.Rev.Lett.77, 2542 (1996).
- [13] M.F.Goman, et al, Phys. Rev. Lett. 85, 170 (2000).
- [14] N. van der Post, et al, Phys. Rev. Lett 73, 2611 (1994).
- [15] E.Scheer, et al., Phys. Rev. Lett. 78, 3535 (1997).
- [16] A. Funusaki and M. Tsukada, Phys. Rev. B 43, 10164 (1991); C W .Beenakker and H.Van Houten, Phys. Rev. Lett. 66, 3056 (1991).
- [17] V.S.Shumeiko, et al, Phys. Rev. B 48, 13129 (1993);
 L.Y.Gorelik, et al, Phys. Rev. Lett. 75, 1162 (1995).
- [18] V S.Shum eiko, E N.Bratus', and G.W endin, in Proceedings of the XXX II M oriond Conference, Les Arcs, 2001, ed.T.M artin, G.M ontam baux, J.Tran Thanh Van (ID P Sciences, 2001).
- [19] V.Ambegaokar, et al, Phys. Rev. Lett. 48, 1745 (1982);
 U.Eckem, et al, Phys. Rev. B 30, 6419 (1984).
- [20] Truncation of the Bogoliubov-de Gennes equation [18] gives the same H am iltonian; Eq. (7) is di erent from the one presented in literature (e.g., D.A. Ivanov and M.V. Feigelm an, Phys. Rev. B 59 8444 (1998)).
- [21] A.Martin-Rodero, et al., Phys. Rev. B 53, R 8891 (1996).
- [22] A J. Leggett, et al., Rev. M od. Phys. 59, 1 (1987).
- [23] D.A. Ivanov and M.V.Feigelm an, JETP Lett. 68, 890 (1998).